









CEU16N10SL

100V ▲ 98mΩ ▲ 12A ▲ Si MOSFET

SILICON Si MOSFET ▲ SMD type

N-channel enhancement mode

UL94V-0 rated flame retardant epoxy

TO252 (DPAK) package ▲ MSL 3

Super high dense cell density for extremely low R_{DS(ON)}

High power and current handling capability

MAXIMUM RATINGS

| Parameter (T_c = 25°C, unless otherwise noted) | | Characteristics |
|--|-----------------------------------|-----------------|
| Drain-Source Voltage | V _{DS} | 100V |
| Gate-Source Voltage | V _{GS} | ±16V |
| Continuous Drain Current at T _C = 25°C | I D | 12A |
| Continuous Drain Current at T _C = 100°C | I D | 8A |
| Pulsed Drain Current Note 1 | I _{DM} Note4 | 48A |
| Maximum Power Dissipation at T _C = 25°C | P _D | 36W |
| Power Dissipation Derating above 25°C | ΔP_D | 0.28W/°C |
| Single Pulsed Avalanche Energy Note 4 | E _{AS} | 36mJ |
| Single Pulsed Avalanche Current Note 4 | I _{AS} | 12A |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55°C to +150°C |

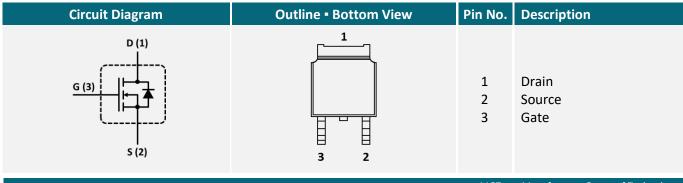
THERMAL CHARACTERISTICS

| Parameter | Symbol | Limit |
|--|--------------------|---------|
| Thermal Resistance, Junction-to-Case | R _{TH_JC} | 3.5°C/W |
| Thermal Resistance, Junction-to-Ambient Note 2 | R _{TH JA} | 50°C/W |

APPLICATIONS

| Battery Management Systems | E-Bike | Industrial Control | Power Inverter | UPS |
|----------------------------|--------|-----------------------|-------------------|-----|
| +4- | 50 | | | |

PIN DESCRIPTION



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ELECTRICAL CHARACTERISTICS ▲ T_C = 25°C, unless otherwise noted

| Item | Condition | Symbol | Min. | Тур. | Max. | Unit |
|--|--|---------------------|------|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = 250\mu A$ | BV _{DSS} | 100 | | | V |
| Zero Gate Voltage Drain Current | $V_{DS} = 100V, V_{GS} = 0V$ | I _{DSS} | | | 1 | μΑ |
| Gate Body Leakage Current, Forward | $V_{GS} = 16V$, $V_{DS} = 0V$ | I _{GSSF} | | | 100 | nA |
| Gate Body Leakage Current, Reverse | $V_{GS} = -16V, V_{DS} = 0V$ | I_{GSSR} | | | -100 | nA |
| On Characteristics Note 3 | | | | | | |
| Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_{D} = 250 \mu A$ | $V_{GS(th)}$ | 0.4 | | 1.4 | V |
| Static Drain-Source On-Resistance | $V_{GS} = 10V$, $I_D = 6A$ | R _{DS(ON)} | | 98 | 120 | mΩ |
| Static Drain-Source On-Resistance | $V_{GS} = 5V$, $I_D = 6A$ | R _{DS(ON)} | | 103 | 130 | mΩ |
| Static Drain-Source On-Resistance | $V_{GS} = 3V$, $I_D = 3A$ | R _{DS(ON)} | | 120 | 165 | mΩ |
| Dynamic Characteristics Note 3 | | | | | | |
| Input Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | C _{ISS} | | 520 | | pF |
| Output Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | Coss | | 120 | | pF |
| Reverse Transfer Capacitance | $V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$ | C_{RSS} | | 35 | | pF |
| Switching Characteristics Note 3 | | | | | | |
| Turn-On Delay Time | $V_{DD} = 50V$, $V_{GS} = 10V$, $I_D = 11A$, $R_{G(ext)} = 6\Omega$ | t _{D(ON)} | | 8 | | ns |
| Turn-On Rise Time | $V_{DD} = 50V$, $V_{GS} = 10V$, $I_D = 11A$, $R_{G(ext)} = 6\Omega$ | t _R | | 4 | | ns |
| Turn-Off Delay Time | $V_{DD} = 50V$, $V_{GS} = 10V$, $I_D = 11A$, $R_{G(ext)} = 6\Omega$ | t _{D(OFF)} | | 34 | | ns |
| Turn-Off Fall Time | V_{DD} = 50V, V_{GS} = 10V, I_D = 11A, $R_{G(ext)}$ = 6Ω | t _F | | 5 | | ns |
| Total Gate Charge | $V_{DS} = 80V$, $V_{GS} = 4.5V$, $I_{D} = 11A$ | Q_{G} | | 9.7 | | nC |
| Gate Source Charge | $V_{DS} = 80V$, $V_{GS} = 4.5V$, $I_{D} = 11A$ | Q _{GS} | | 0.9 | | nC |
| Gate Drain Charge | $V_{DS} = 80V$, $V_{GS} = 4.5V$, $I_{D} = 11A$ | Q_{GD} | | 5.3 | | nC |
| Drain-Source Diode Characteristics a | nd Maximum Ratings | | | | | |
| Drain-Source Diode Forward Current | | Is | | | 12 | Α |
| Drain-Source Diode Forward Voltage Note 2 | V _{GS} = 0V, I _S = 12A | V_{SD} | | | 1.5 | V |

Notes

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 3: Guaranteed by design, not subject to production testing.
- 4: Pulse width limited by safe operating area.
- 5: L = 0.5mH, $I_{AS} = 12$ A, $V_{DD} = 25$ V, $R_G = 25$ Ω, Starting $T_J = 25$ °C

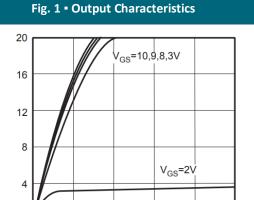


D, Drain Current (A)

0

0

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V_{DS}, Drain-to-Source Voltage (V)

10

Fig. 2 • Transfer Characteristics

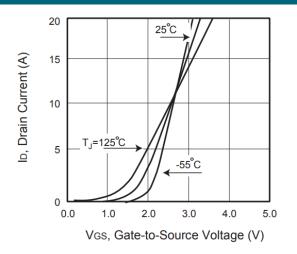


Fig. 3 • Capacitance

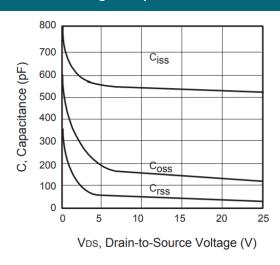


Fig. 4 • On-Resistance Variation with Temperature

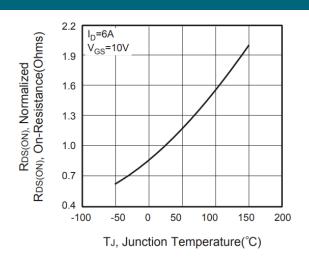


Fig. 5 • Gate Threshold Variation with Temperature

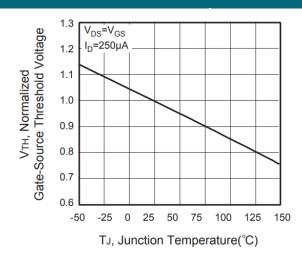
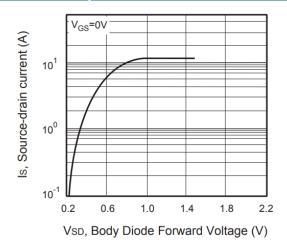


Fig. 6 • Body Diode Forward Voltage Variation with Source Current



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Fig. 7 • Gate Charge

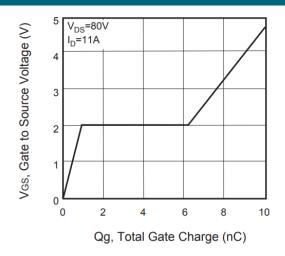


Fig. 8 • Maximum Safe Operating Area

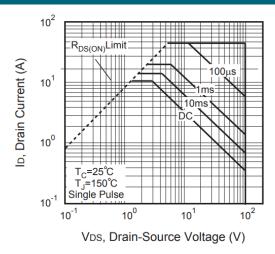


Fig. 9 • Breakdown Voltage Variation vs. Temperature

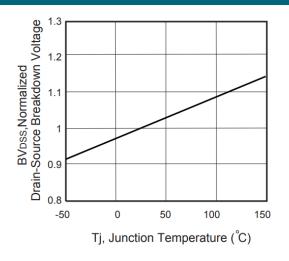
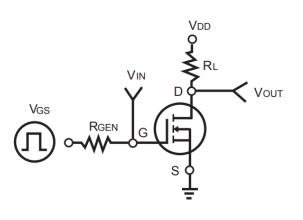
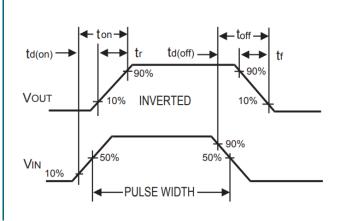


Fig. 10 • Switching Test Circuit

Fig. 11 • Switching Waveforms

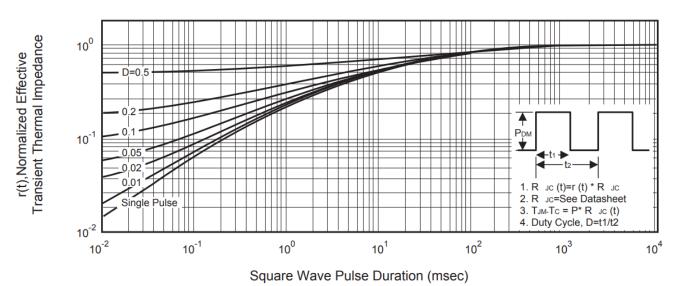




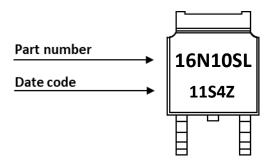


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Fig. 12 • Normalized Thermal Transient Impedance Curve



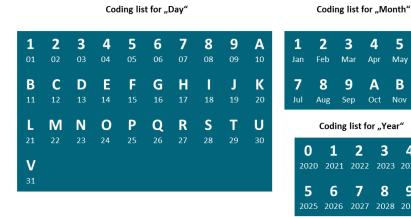
PART MARKING



DATE CODE

Example: 11S4Z





4 5 6

A В C

> 3 4

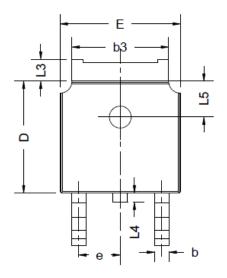
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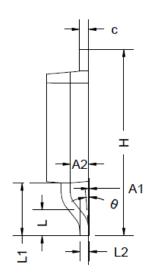
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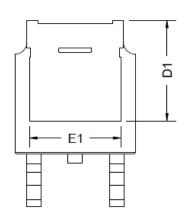
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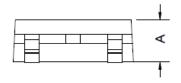


PACKAGE OUTLINE









| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) | |
|-----|-----------------------|-----------------------|--------------------|--|
| Α | 2.20 | 2.30 | 2.38 | |
| A1 | 0.00 | - | 0.20 | |
| A2 | A2 0.90 1.07 | | 1.17 | |
| b | 0.68 0.78 | | 0.90 | |
| b3 | 5.23 | 5.33 | 5.46 | |
| С | 0.43 0.53 | | 0.61 | |
| D | 5.98 6.10 | | 6.22 | |
| D1 | | | | |
| Е | 6.40 6.60 | | 6.73 | |
| E1 | 4.63 | - | - | |

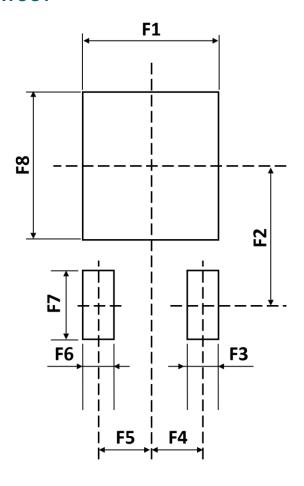
| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) | | | |
|-----|--------------------|--------------------|--------------------|--|--|--|
| е | | 2.286 BSC | | | | |
| Н | 9.40 | 10.10 | 10.50 | | | |
| L | 1.38 | 1.50 | 1.75 | | | |
| L1 | 2.90 REF | | | | | |
| L2 | | 0.51 BSC | | | | |
| L3 | 0.88 | - | 1.28 | | | |
| L4 | 0.50 | | 1.00 | | | |
| L5 | 1.65 | 1.80 | 1.95 | | | |
| θ | 0° | - | 8° | | | |

ORDERING INFORMATION

| Part Number | Package | Packing | Reel Qty. | Inner Box Qty. | Outer Box Qty. |
|-------------|--------------|---------|-----------|----------------|----------------|
| CEU16N10SL | TO252 (DPAK) | Reel | 2,500pcs | 5,000pcs | 40,000pcs |



RECOMMENDED PAD LAYOUT



| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) | |
|-----|-----------------------|--------------------|--------------------|--|
| F1 | - | 6.00 | - | |
| F2 | - | - | | |
| F3 | - | 1.40 | - | |
| F4 | - | 2.29 | - | |

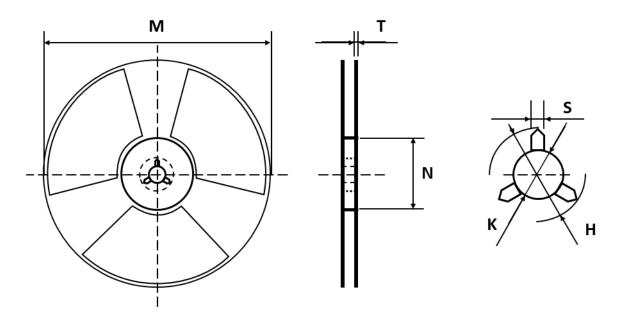
| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|-----------------------|-----------------------|--------------------|
| F5 | - | 2.29 | - |
| F6 | - | 1.40 | - |
| F7 | - | 3.00 | - |
| F8 | - | 6.50 | - |

Notes:

- 1. The suggested land pattern dimensions have been provided for reference only.
- 2. For further information, please reference document IPC-7351A.

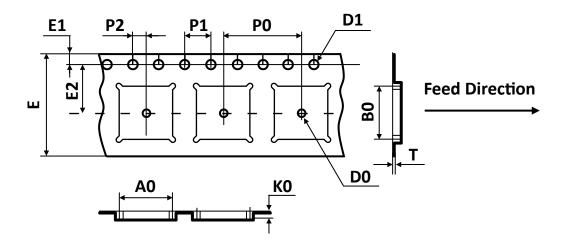


REEL DIMENSIONS ▲ All dimensions in mm



| Tape Size | Reel Size | M | N | T | Н | K | S |
|-----------|-----------|---------|---------|-------|-------|-------|-------|
| | | Ø330.00 | Ø100.00 | 2.10 | 22.00 | 13.00 | 2.00 |
| 16mm | Ø330 | ±2.00 | ±0.50 | ±0.20 | ±0.50 | +0.50 | +0.50 |
| | | 12.00 | ±0.50 | ±0.20 | ±0.50 | -0.20 | -0.20 |

TAPE DIMENSIONS ▲ All dimensions in mm

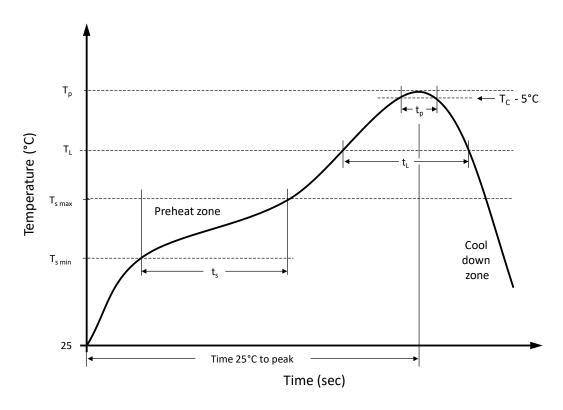


| Package | A0 | В0 | КО | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | Т |
|---------|-------|-------|-------|------|-------|-------|-------|-------|-------|-------|-------|-------|
| TO252 | 6.90 | 10.50 | 2.70 | 1.50 | 1.50 | 16.00 | 1.75 | 7.50 | 8.00 | 4.00 | 2.00 | 0.30 |
| (DPAK) | ±0.10 | ±0.10 | ±0.10 | MIN | ±0.10 | +0.30 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.10 | ±0.05 |

Note: All dimensions meet EIA-481-D requirements.



RECOMMENDED REFLOW SOLDERING PROFILE



Recommended reflow soldering conditions ▲ **Refer to JEDEC J-STD-020E**

| Profile Features | | Sn-Pb Eutetic Assembly | Pb-Free Assembly |
|---|--------------------|------------------------|------------------|
| Preheat temperature min. | $T_{s min}$ | 100 °C | 150 °C |
| Preheat temperature max. | T _{s max} | 150 °C | 200 °C |
| Preheat time t _s from T _{s min} to T _{s max} | ts | 120 seconds | 120 seconds |
| Ramp-up rate (T₁ to Tp) | | max. 3 °C/second | max. 3 °C/second |
| Liquidous temperature | T_L | 183 °C | 217 °C |
| Time t _L maintained above T _L | t _L | 150 seconds max. | 150 seconds max. |
| Peak package body temperature | Tp | 235°C | 260°C |
| Timeframe of within 5°C below and up to max actual peak body temperature | t _p | 20 seconds max. | 30 seconds max. |
| Ramp-down rate (T _L to T _p) | | max. 6 °C/second | max. 6 °C/second |
| Time 25°C to peak temperature | | max. 6 minutes | max. 8 minutes |



REVISION TABLE

| Revision | Date | Status | Notes |
|----------|------------|-----------------|---------------------|
| 001 | 30/09/2022 | Initial release | Initial publication |
| | | | |
| | | | |
| | | | |
| | | | |
| | | | |

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